



INFORMATION DISCLOSURE CITATION (Use several sheets if necessary)

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10/764,193

APPLICANT(S):

MICHAEL MCSWINEY, ET AL.

FILING DATE:

January 23, 2004

GROUP ART UNIT:

U.S. PATENT DOCUMENTS

*EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
	A.						
	B.						
	C.						
	D.						
	E.						
	F.						
	G.						
	H.						
	I.						

FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
							YES	NO
	J.							
	K.							
	L.							
	M.							

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

/RB/	N.	Inventors: Michael L. McSwiney and Michael D. Goodner, Patent Application entitled: <i>Low-Temperature Silicon Nitride Deposition</i> , filed July 30, 2003, Serial No. 10/631,627, Patent Application has 15 pages and 4 pages of drawings
/RB/	O.	Author: SCHUMACHER, A UNIT OF AIR PRODUCTS AND CHEMICALS, INC.; entitled: <i>BTBAS Silicon Nitride</i> ; 1 page; www.schumacher.com/btbas , date unknown.
	P.	
	Q.	
	R.	
	S.	
	T.	

EXAMINER

/Renee Berry/

DATE CONSIDERED

10/01/2007

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.